

/ Descriptions

WR0459 M M E QSQ æ M ç s ll 1 Silicon NPN transistor in a TO-126 Plastic Package.

/ Features

æ I ð S_F@418 Z ε Ta@58 † ζ

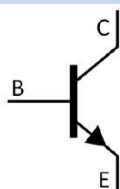
High Power Dissipation :P_C=1.5W(Ta=25).

/ Applications

æ æ H ç ð ll ت ð ç я I æ ç ll

Low collector saturation voltage ,large current.

/ Equivalent Circuit



/ Pinning



PIN1 χ Emitter

PIN 2 χ Collector

PIN 3 χ Base

/ h_{FE} Classifications & Marking

ø M ç ð ” See Marking Instructions.

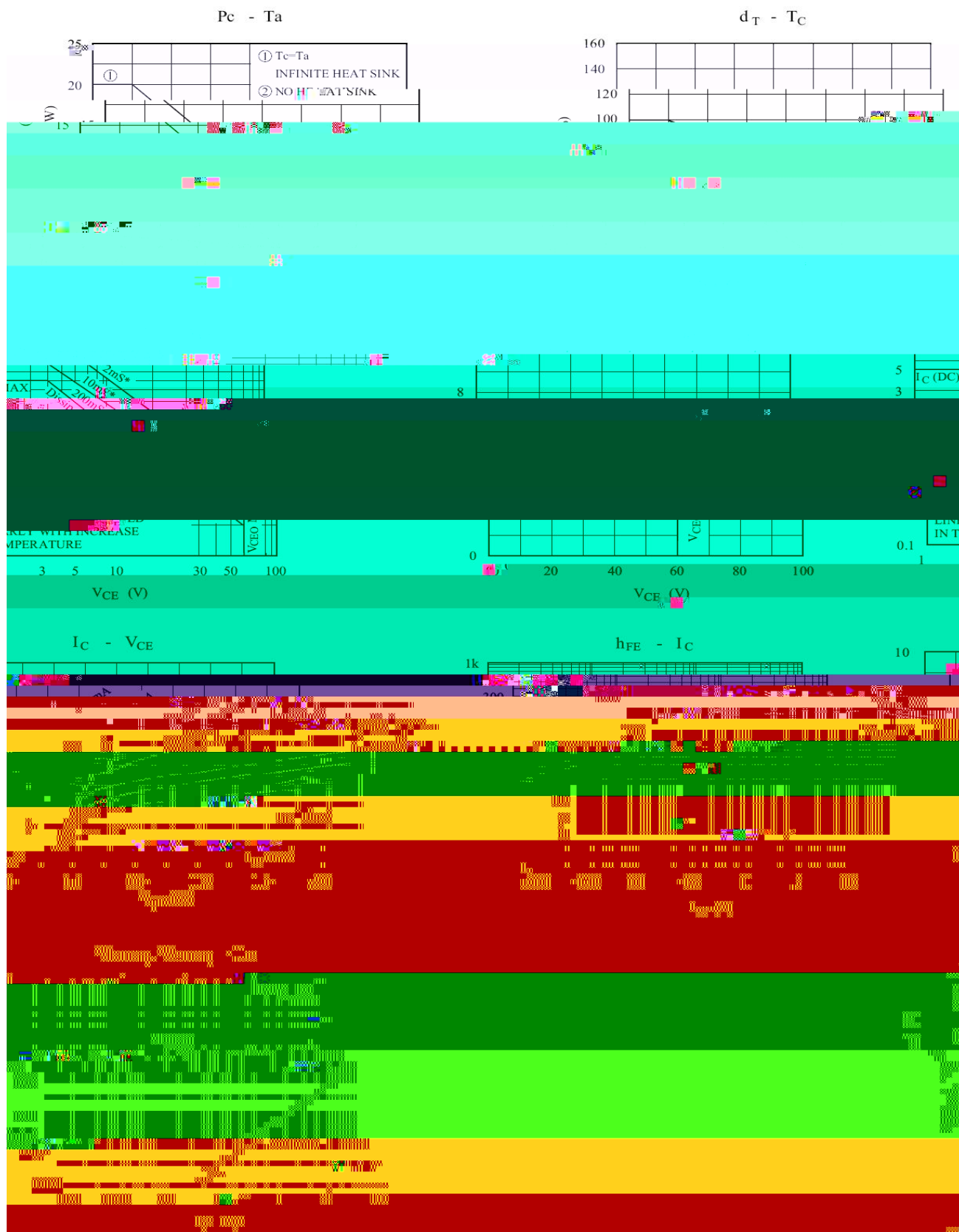
/ Absolute Maximum Ratings(Ta=25 °C)

Parameter	Symbol	Rating	Unit
Collector to Base Voltage	V_{CBO}	60	V
Collector to Emitter Voltage	V_{CEO}	60	V
Emitter to Base Voltage	V_{EBO}	7.0	V
Collector Current - Continuous	I_C	5.0	A
Peak Collector Current	I_{CP}	8.0	A
Base Current - Continuous	I_B	1.0	A
Collector Power Dissipation	P_C	1.5	W
Collector Power Dissipation	$P_C(T_c=25^\circ C)$	20	W
Junction Temperature	T_j	150	
Storage Temperature Range	T_{stg}	-55 ~ 150	

/ Electrical Characteristics(Ta=25 °C)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Collector Cut-off Current	I_{CBO}	$V_{CB}=50V$ $I_E=0$			10	A
Emitter Cut-off Current	I_{EBO}	$V_{EB}=7V$ $I_C=0$			10	A
DC Current Gain	$h_{FE(1)}$	$V_{CE}=1.0V$ $I_C=2.0A$	100		400	
	$h_{FE(2)}$	$V_{CE}=1.0V$ $I_C=0.1A$	60			
	$h_{FE(3)}$	$V_{CE}=2.0V$ $I_C=5.0A$	50			
Collector to Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=2.0A$ $I_B=0.2A$		0.1	0.3	V
Base to Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=2.0A$ $I_B=0.2A$		0.9	1.2	V
Turn On Time	t_{on}	$V_{CC}=10V$ $I_B=0.2A$		0.2	1	s
Fall Time	t_f			1.1	2.5	s
Storage Time	t_s			0.2	1	s

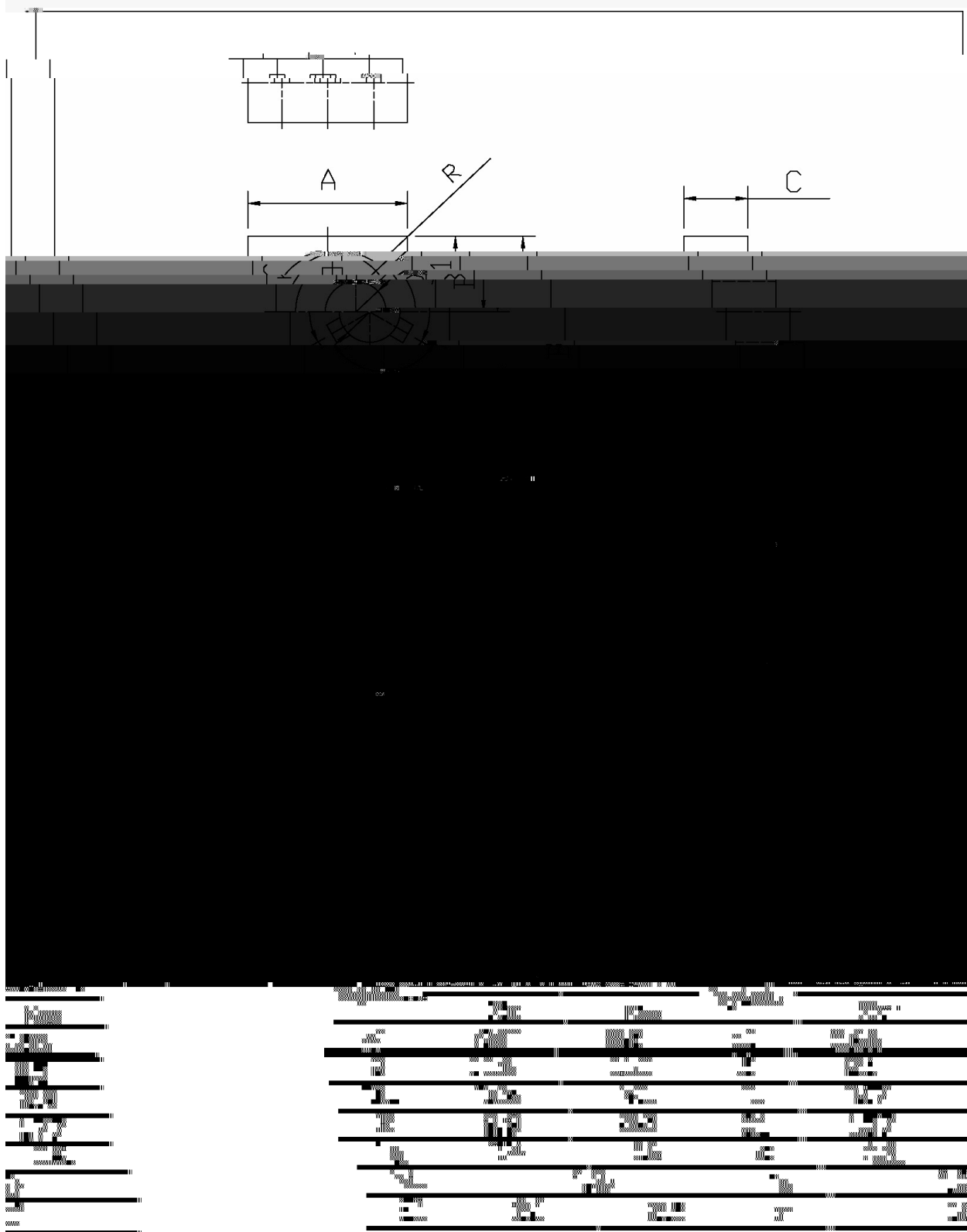
/ Electrical Characteristic Curve



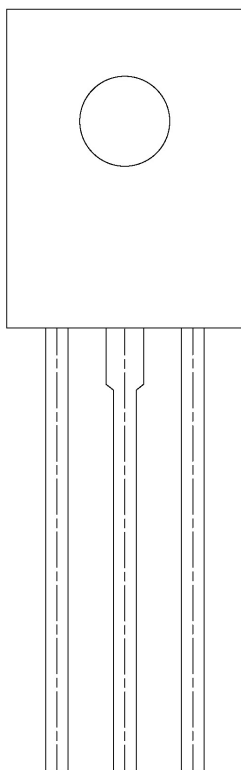
/ Package Dimensions

TQ-126

单位: mm



/ Marking Instructions



— " X

EU X

G49<4 X

---- X

Note:

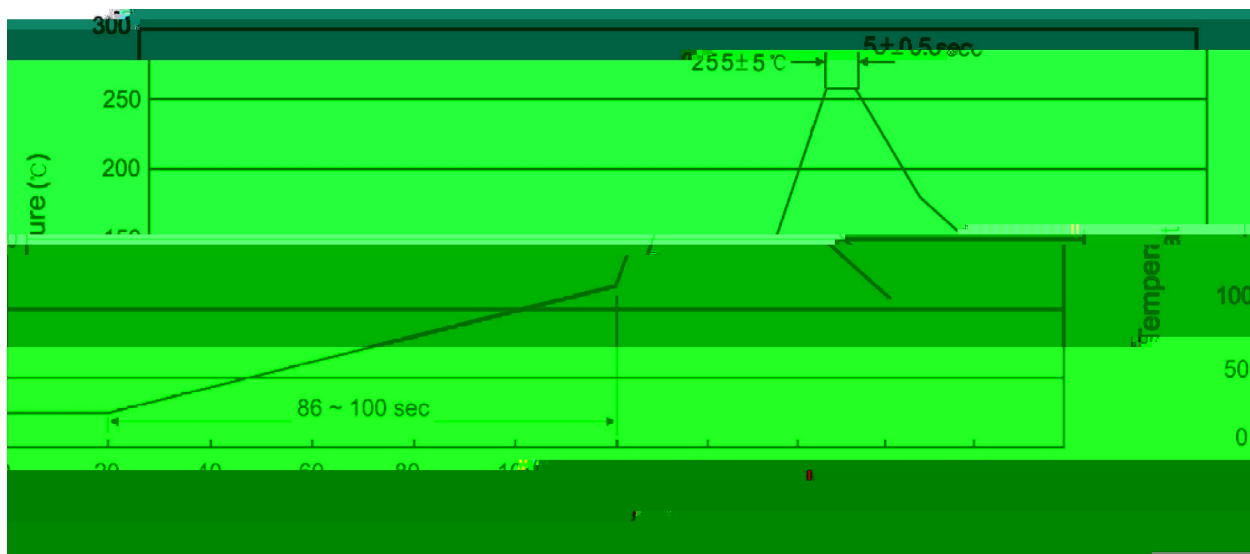
BR:

— 3 " Γ

— 3 " Γ

— 1 F Ǳ " Γ 1 Ǳ 1 F Ǳ " Ψ ρ

() / Temperature Profile for Dip Soldering(Pb-Free)



说明

1. 预加热: 25~150℃, 时间: 60~90sec;
2. 峰值温度: 255±5℃, 时间: 5±0.5sec;
3. 冷却速度: 2~10℃/sec.

Note:

- 1.Preheating:25~150℃, Time:60~90sec.
- 2.Peak Temp.:255±5℃, Duration:5±0.5sec.
3. Cooling Speed: 2~10℃/sec.

/ Resistance to Soldering Heat Test Conditions

温度: 270±5℃ 时间: 10±1 sec. Temp.:270±5 Time:10±1 sec

/ Packaging SPEC.

散装 / BULK

Package Type	Units					Dimension (unit mm ³)		

管装 / TUBE

Package Type	Units					Dimension (unit mm ³)		

/ Notices